

Surface Enhanced Raman Scattering of Alkyne Conjugated MoS₂: A Comparative Study between Metallic and Semiconductor Phase

Rajeshkumar Anbazhagan^a, Adhisankar vadivelmurugan^a, Hsieh-Chih Tsai*^a and Ru-Jong Jeng*^b

a. Graduate Institute of Applied Science and Technology, National Taiwan University of Science and Technology, Taipei 106, Taiwan.

b. Institute Polymer Science and Engineering, National Taiwan University, Taipei 106, Taiwan

[*] To whom correspondence and reprint requests should be addressed.

Prof. Hsieh-Chih Tsai

E-mail:h.c.tsai@mail.ntust.edu.tw

Tel+886-2-27303625

Prof. Ru-Jong Jeng

E-mail: rujong@ntu.edu.tw;

Tel: +886-2-33665884

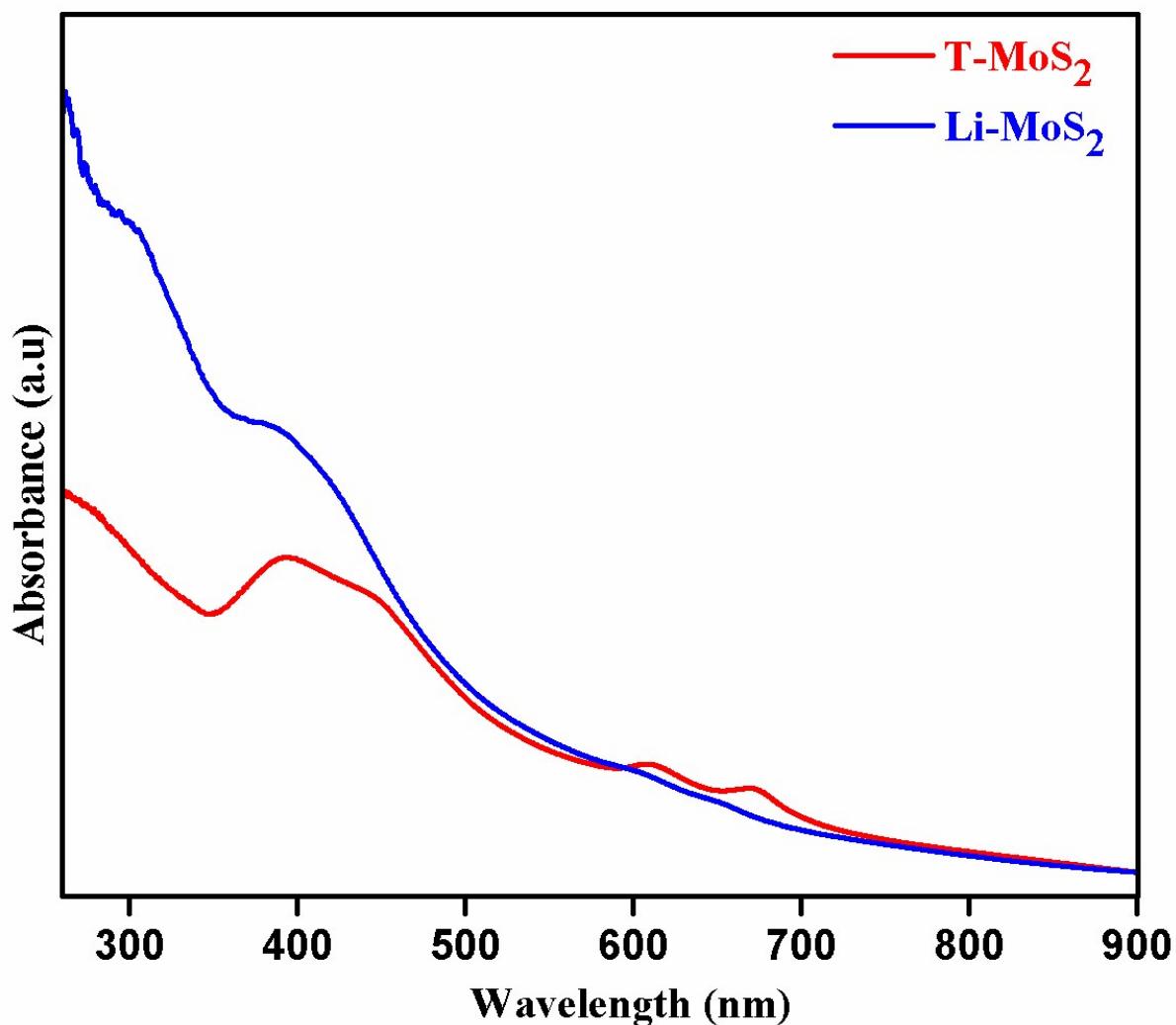


Figure S1: Uv-visible absorption spectrum of T-MoS₂ and Li-MoS₂.

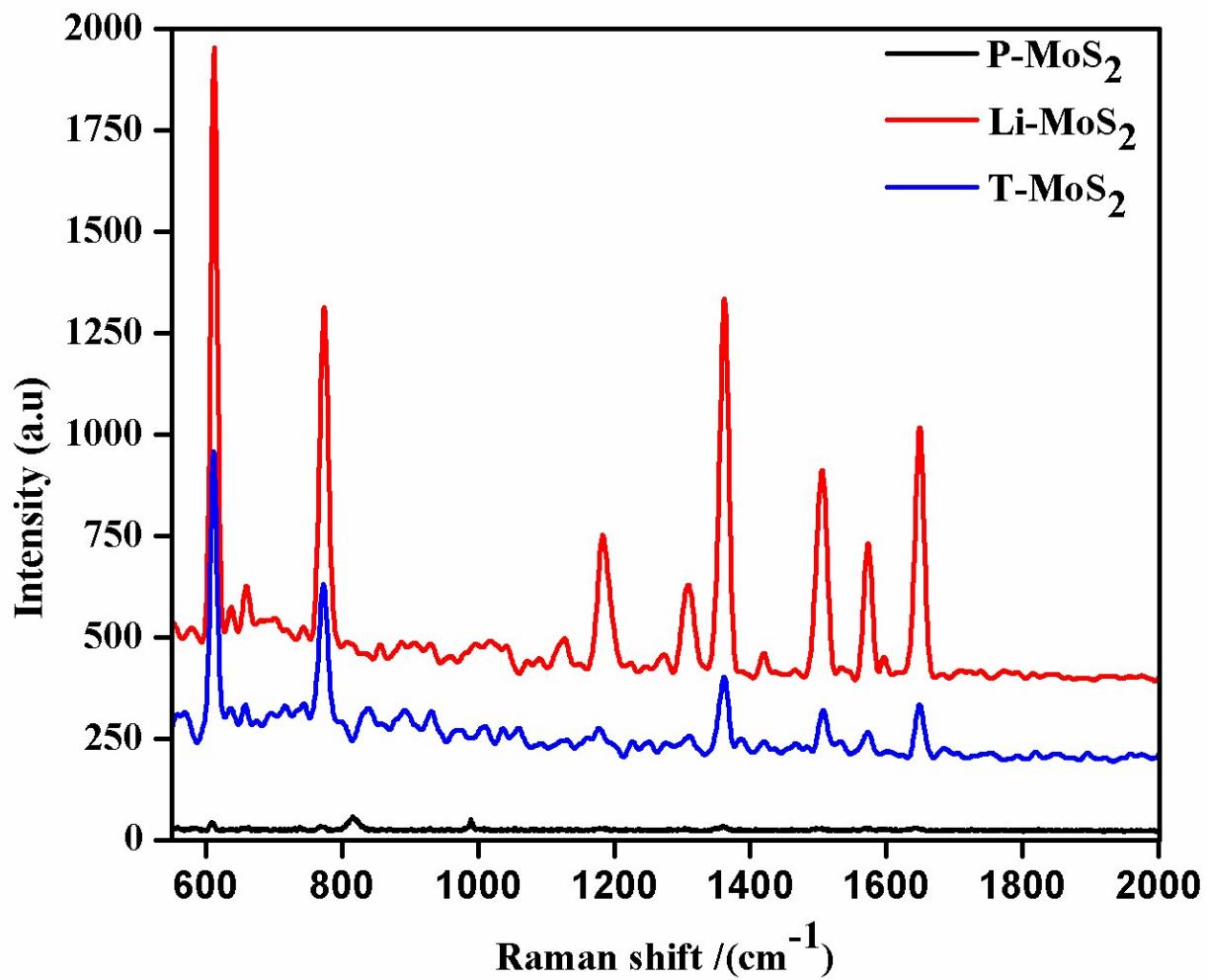


Figure S2: SERS of 1 μM R6G in different MoS₂ system.

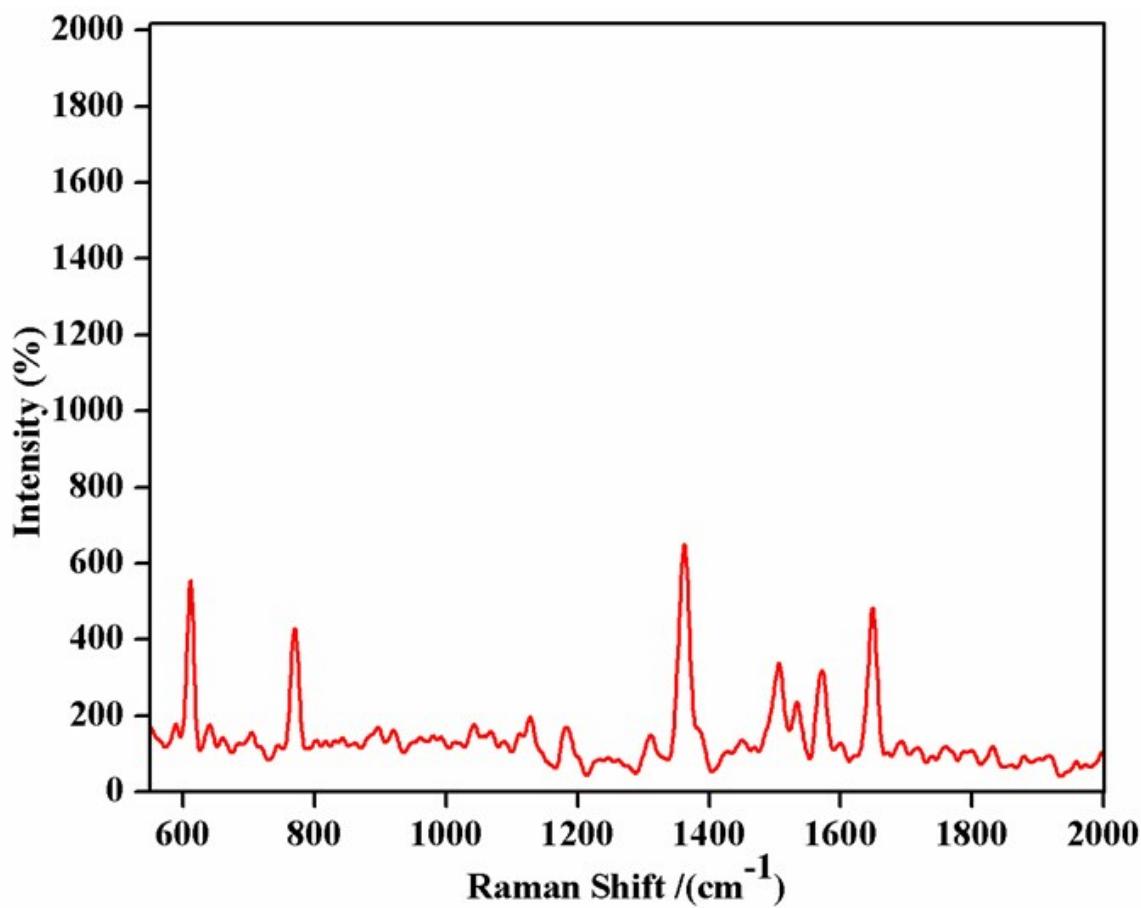


Figure S3: Raman spectrum of only R6G molecule.

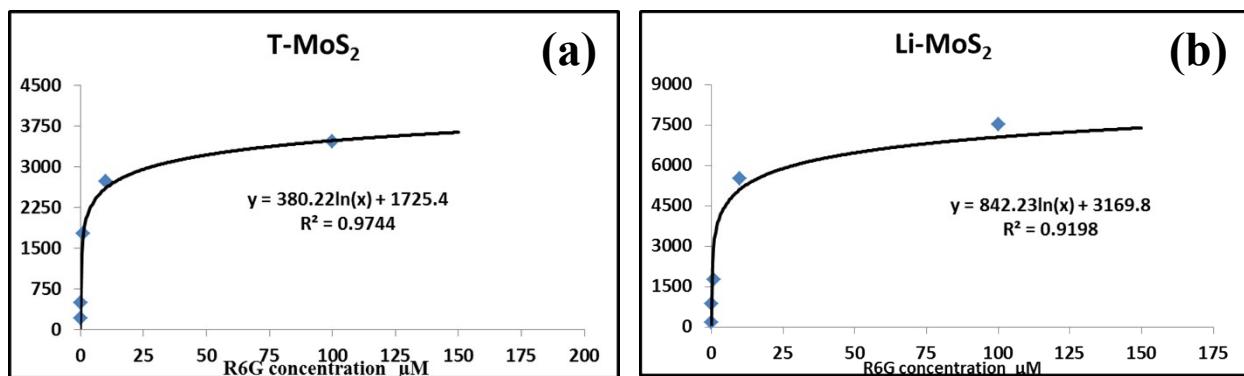


Figure S4: SERS intensity of the band at 611 cm^{-1} versus increasing concentration of R6G in Li-MoS₂ and T-MoS₂, and fitting to a Langmuir curve.

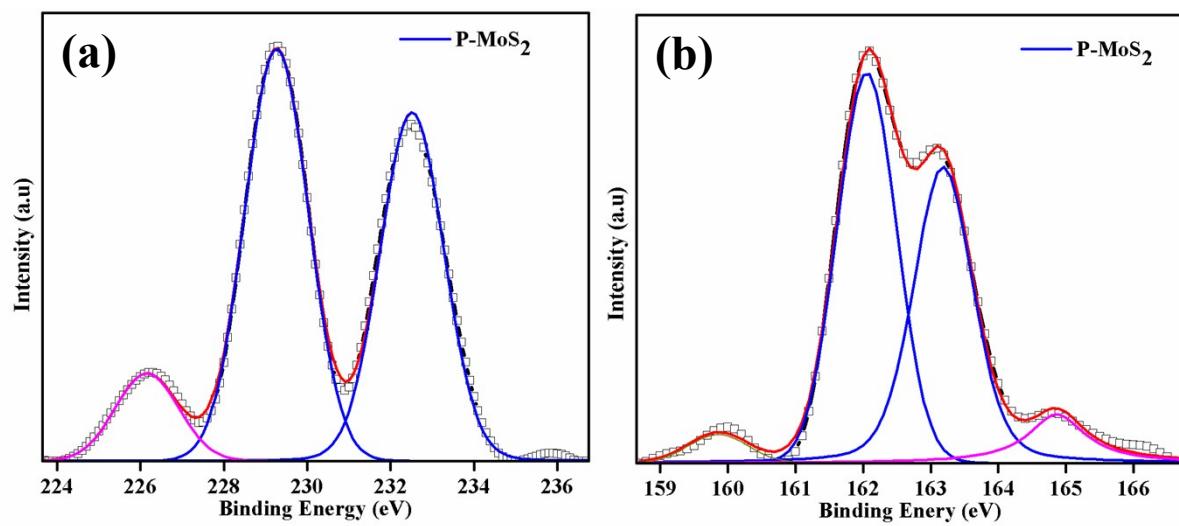


Figure S5: XPS binding energy spectrum of P-MoS₂. a) Mo 3d, b) S 2p binding energy.

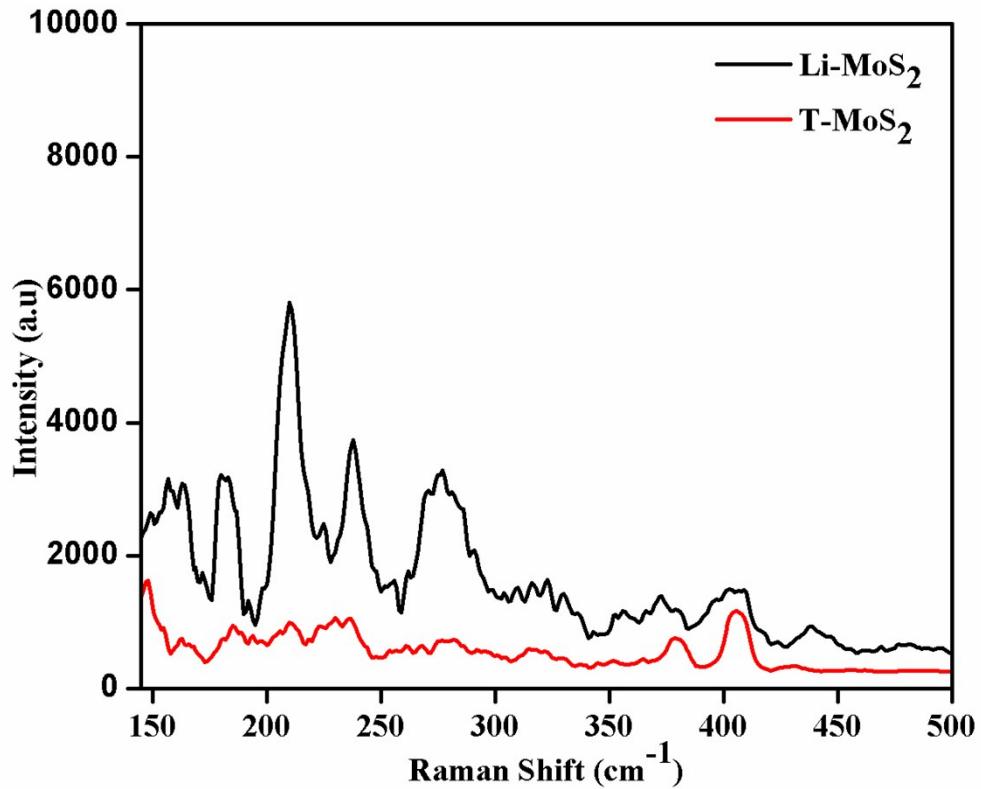


Figure S6: Raman spectrum of Li-MoS₂ and T-MoS₂.

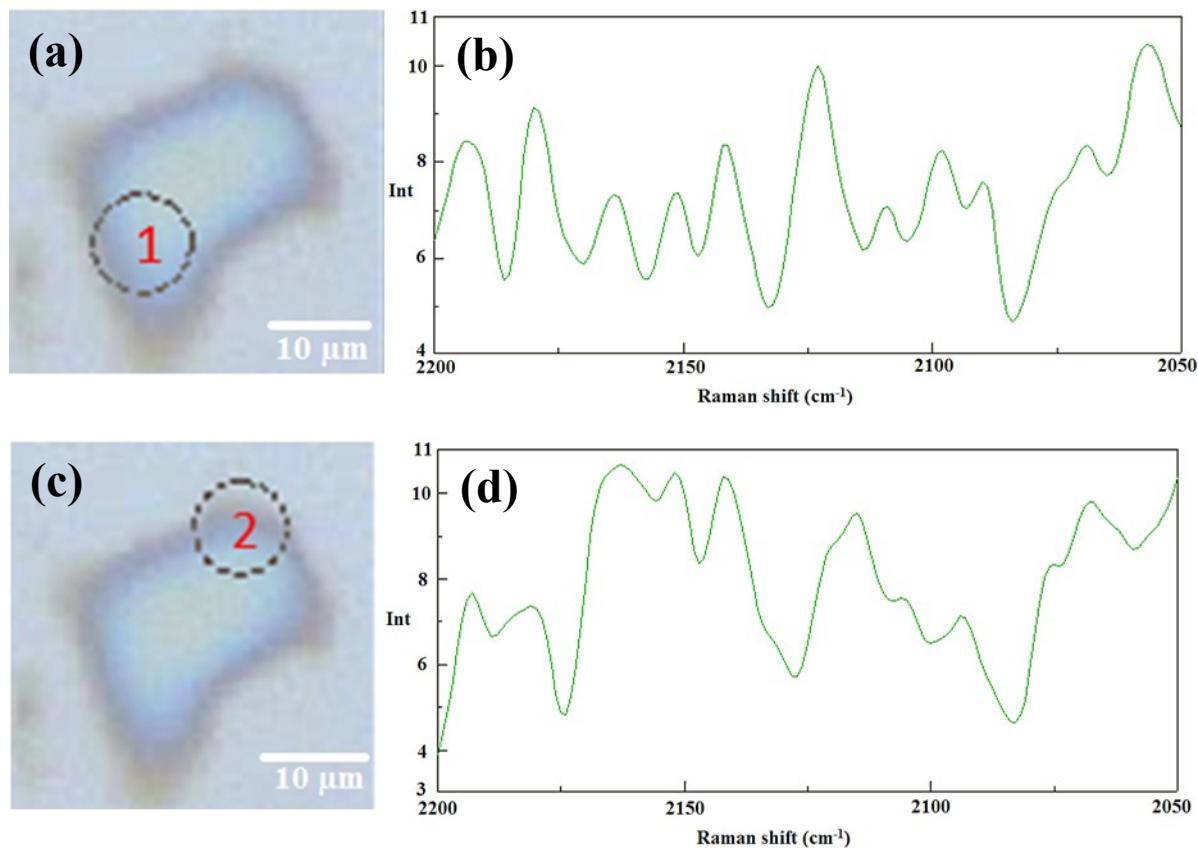


Figure S7: Optical and SERS spectrum of T-MoS₂-Alk. a and c) Optical image and corresponding SERS spectrum b and d) of T-MoS₂-Alk.

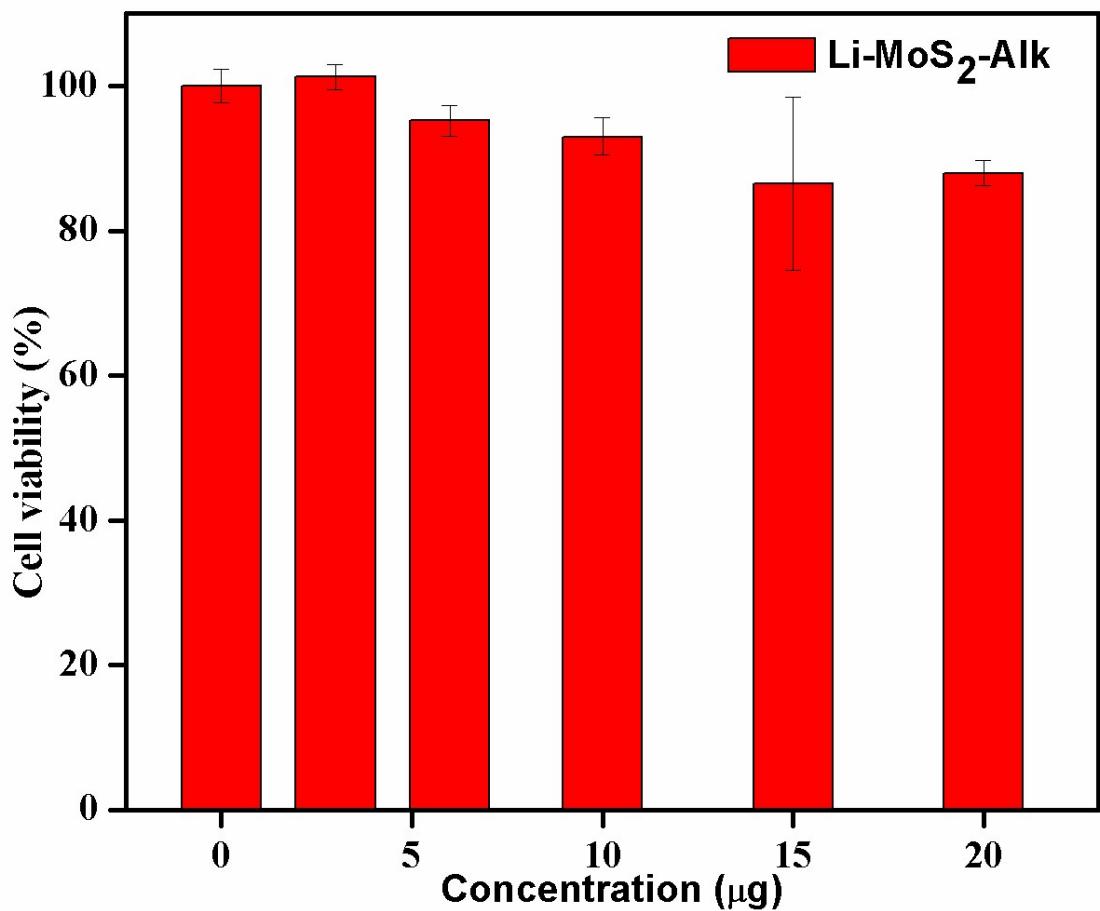


Figure S8: Cell viability of Li-MoS₂-Alk.